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Europäisches Patentamt

European Patent Offic

Offic uropéen des brev ts



(11) Publication number: 0 529 963 A3

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EUROPEAN PATENT APPLICATION

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(51) Int. Cl.⁵: **C30B 11/00**, C30B 29/60, G02B 1/10, G02B 1/02

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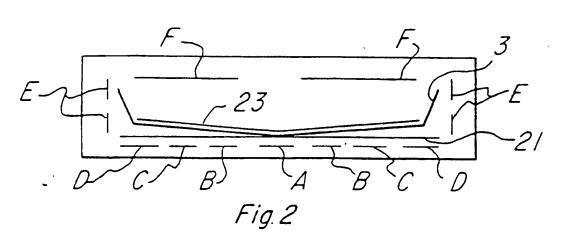
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(54) Crystal growth process for large area GaAs and infrared window/dome made therefrom.

An optical dome or window formed of a composition which is transmissive to infrared frequencies in the range of from about 1 micron to about 14 microns and which is relatively opaque to substantially all frequencies above about 14 microns consisting essentially of a compound taken from the class consisting of group III-V compounds doped with an element taken from the class consisting of shallow donors and having less than about 1 x 10⁷ atoms/cc impurities and having less than about 1 x 10¹⁵ parts carbon. The shallow donors are Se, Te and S, preferably Se, with the Se concentration from 5 x 10¹⁵ atoms/cc to 2 x 10¹⁶ atoms/cc. The group III-V compound is preferably GaAs or GaP. The group III-V compound is fabricated by providing a graphite vessel (3) containing a graphite cloth (23) with the molten group III element thereover, a shallow donor and water containing boron oxide thereover, loading the group V element into the vessel in essentially stoichiometric amounts to provide the molten compound of the group III and group V elements and cooling the molten compound progressively in a vertical direction from bottom to top to form a crystal by causing growth of the crystal from the bottom up in a vertical direction. The crystal with B₂O₃ thereon is then placed in a vacuum to reboil the B₂O₃ and cause it to foam. The B₂O₃ is then easily removed from the crystal.







EUROPEAN SEARCH REPORT

Application Number EP 92 30 7647

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Category	of relevant pas		to claim	
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	THE HAGUE	20 March 1995	_	Examiner Cook, S
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European Patent

Office

CL	AIMS INCURRING FEES
The presen	t European patent application comprised at the time of filing more than ten claims.
	All claims fees have been paid within the prescribed time limit. The present European search report has been
	drawn up for all claims.
	Only part of the claims fees have been paid within the prescribed time limit. The present European search
	report has been drawn up for the first ten claims and for those claims for which claims fees have been paid,
	namely claims:
	No claims fees have been paid within the prescribed time limit. The present European search report has been
	drawn up for the first ten claims.
LA	CK OF UNITY OF INVENTION
	Division considers that the present European patent application does not comply with the requirement of unity of
	relates to several inventions or groups of inventions,
namely.	
se	ee sheet -B-
[X]	All further search fees have been paid within the fixed time limit. The present European search report has
<u> </u>	been drawn up for all claims.
	Only part of the further search fees have been paid within the fixed time limit. The present European search
	report has been drawn up for those parts of the European patent application which relate to the inventions in respects of which search fees have been paid,
	namely claims:
	None of the further search fees has been paid within the fixed time limit. The present European search report
	has been drawn up for those parts of the European patent application which relate to the invention first mentioned in the claims,
L	namely claims:



EUROPEAN SEARCH REPORT

Application Number EP 92 30 7647

Category	Citation of document with ir of relevant pac	ndication, where appropriate, ssages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int.CL5)
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A	DE-A-34 41 707 (RIN * page 7, line 9 -		23	
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	THE HAGUE	20 March 1995	Cod	ok, S .
X: particularly relevant if taken alone after the fills Y: particularly relevant if combined with another D: document cit document of the same category L: document cit A: technological background		d in the application I for other reasons	lished on, or	

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EUROPEAN SEARCH REPORT

Application Number EP 92 30 7647

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ategory	of relevant pas		to claim	APPLICATION (Int.CL5)
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CATEGORY OF CITED DOCUMENTS X: particularly relevant if taken alone Y: particularly relevant if combined with another socument of the same category A: technological background		NTS T: theory or princip E: earlier patent do after the filing d other D: document cited	T: theory or principle underlying the invention E: earlier patent document, but published on, or after the filing date D: document cited in the application L: document cited for other reasons	



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EP 92 30 7647 -B-

LACK OF UNITY OF INVENTION

The Search Division considers that the present European patent application does not comply with the requirement of unity of invention and relates to several inventions or groups of inventions, namely:

1. Claims 1-17 : Optical window III-V material and method of preparing it.

2. Claims 18-22: Method of removing B_2O_3 encapsulant.

3. Claims 23-25 : Method of making compound semiconductor material.

4. Claim 26 : Method of making Si and Ge crystals.

5. Claims 27-29 : Crystalline material having certain resistivity.